

## FDD8447L\_F085

### N-Channel PowerTrench® MOSFET

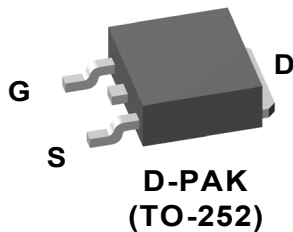
40V, 50A, 11.0mΩ

#### Features

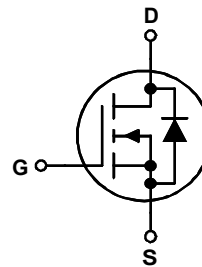
- Typ  $r_{DS(on)}$  = 7.0mΩ at  $V_{GS}$  = 10V,  $I_D$  = 14A
- Typ  $r_{DS(on)}$  = 8.5mΩ at  $V_{GS}$  = 4.5V,  $I_D$  = 11A
- Fast Switching
- Qualified to AEC Q101
- RoHS Compliant

#### Applications

- Inverter
- Power Supplies
- Automotive Engine Control
- Power Train Management
- Solenoid and Motor Drivers
- Electronic Transmission
- Primary Switch for 12V and 24V Systems



**D-PAK  
(TO-252)**



## MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Rated	Units
$V_{DSS}$	Drain to Source Voltage (Note 1)	40	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current Continuous ( $T_C < 80^\circ\text{C}$ , $V_{GS} = 10\text{V}$ )	50	A
	Pulsed	See Figure 4	
$E_{AS}$	Single Pulse Avalanche Energy (Note 2)	40	mJ
$P_D$	Power Dissipation	65	W
	Dereate above $25^\circ\text{C}$	0.43	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature	-55 to + 175	$^\circ\text{C}$

## Thermal Characteristics

$R_{\theta JC}$	Maximum Thermal Resistance Junction to Case	2.3	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-252, 1in <sup>2</sup> copper pad area	40	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8447L	FDD8447L_F085	D-PAK(TO-252)	13"	12mm	2500 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$B_{VDSS}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$	40	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 32\text{V}$ , $V_{GS} = 0\text{V}$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	1.0	1.9	3.0	V
$r_{DS(on)}$	Drain to Source On Resistance	$I_D = 14\text{A}$ , $V_{GS} = 10\text{V}$	-	7.0	8.5	m $\Omega$
		$I_D = 11\text{A}$ , $V_{GS} = 4.5\text{V}$	-	8.5	11.0	
		$I_D = 14\text{A}$ , $V_{GS} = 10\text{V}$ , $T_J = 125^\circ\text{C}$	-	10.4	14.0	
$g_{FS}$	Forward Transconductance	$I_D = 14\text{A}$ , $V_{DS} = 5\text{V}$	-	58	-	S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 20\text{V}$ , $V_{GS} = 0\text{V}$ , $f = 1\text{MHz}$	-	1970	-	pF	
$C_{oss}$	Output Capacitance		-	250	-	pF	
$C_{rss}$	Reverse Transfer Capacitance		-	150	-	pF	
$R_g$	Gate Resistance	$f = 1\text{MHz}$	-	1.27	-	$\Omega$	
$Q_g(TOT)$	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V	$V_{DD} = 20\text{V}$ $I_D = 14\text{A}$ $V_{GS} = 10\text{V}$	-	37	52	nC
$Q_g(5)$	Total Gate Charge at 5V	$V_{GS} = 0$ to 5V		-	20	28	nC
$Q_{gs}$	Gate to Source Gate Charge			-	6	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge			-	7	-	nC

**Electrical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Switching Characteristics**

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 20\text{ V}, I_D = 1\text{ A},$ $V_{GS} = 10\text{ V}, R_{GEN} = 6\ \Omega$	-	12	21	ns
$t_r$	Rise Time		-	12	21	ns
$t_{d(off)}$	Turn-Off Delay Time		-	38	61	ns
$t_f$	Fall Time		-	9	18	ns

**Drain-Source Diode Characteristics**

$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 14\text{ A}$	-	0.8	1.2	V
$t_{rr}$	Reverse Recovery Time	$I_F = 14\text{ A}, dI_{SD}/dt = 100\text{ A}/\mu\text{s}$	-	22	29	ns
$Q_{rr}$	Reverse Recovery Charge		-	11	14	nC

**Notes:**

- 1: Starting  $T_J = 25^\circ\text{C}$  to  $175^\circ\text{C}$ .
- 2: Starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.05\text{ mH}$ ,  $I_{AS} = 40\text{ A}$

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: <http://www.aecouncil.com/>  
 All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

### Typical Characteristics

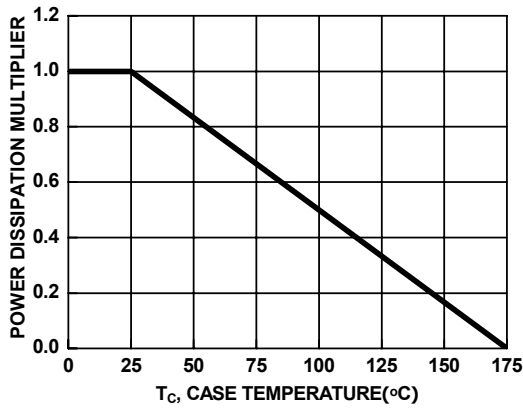


Figure 1. Normalized Power Dissipation vs Case Temperature

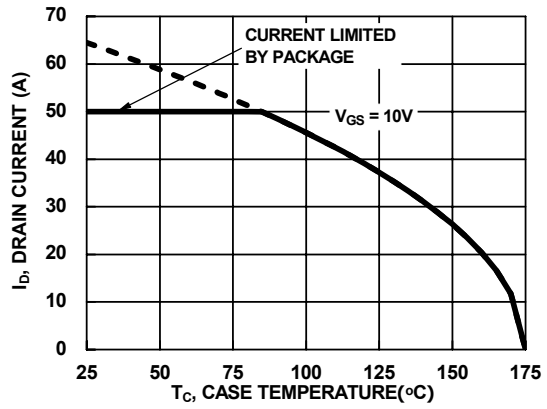


Figure 2. Maximum Continuous Drain Current vs Case Temperature

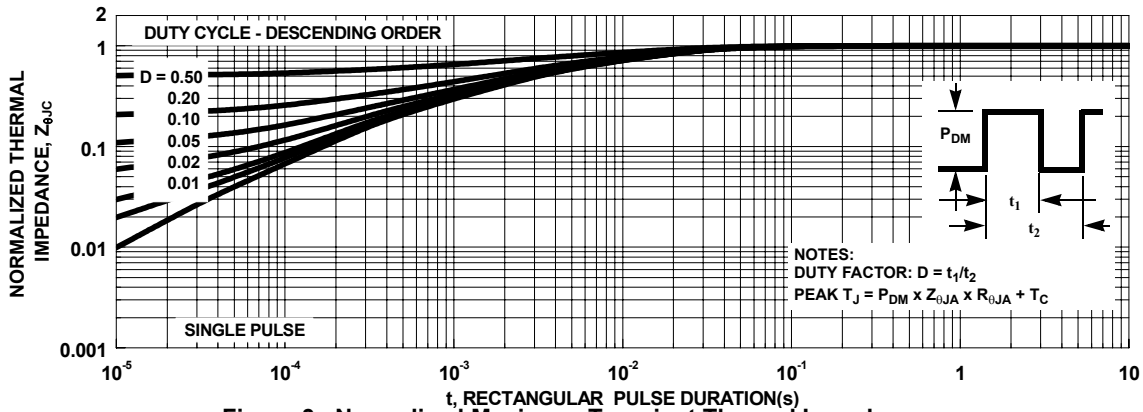


Figure 3. Normalized Maximum Transient Thermal Impedance

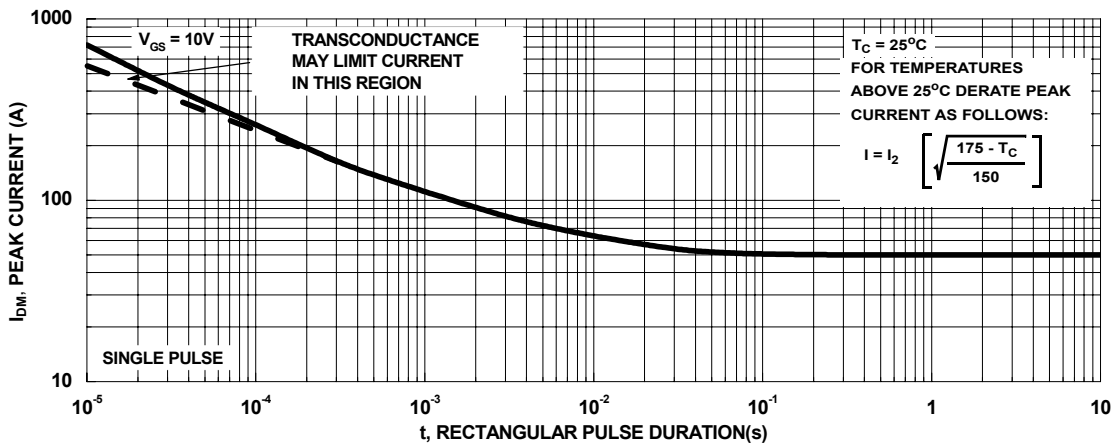


Figure 4. Peak Current Capability

## Typical Characteristics

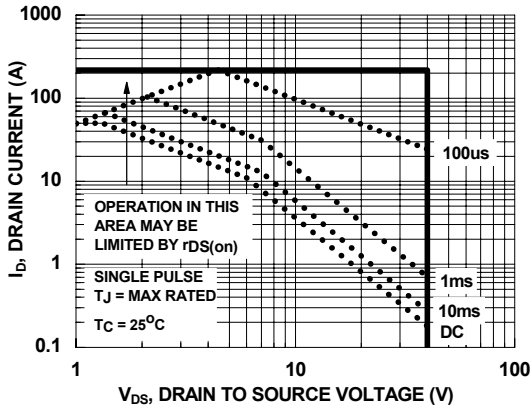
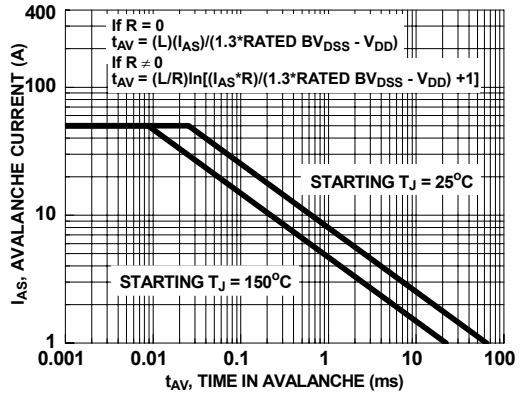


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515  
 Figure 6. Unclamped Inductive Switching Capability

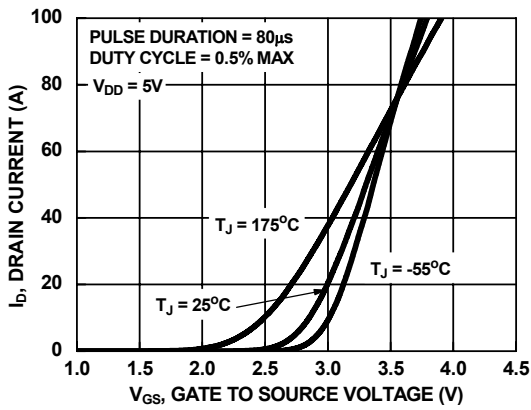


Figure 7. Transfer Characteristics

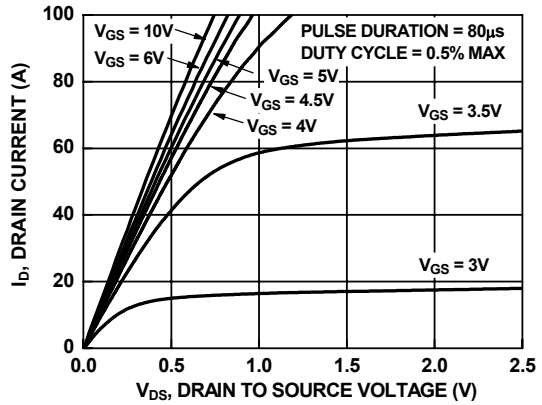


Figure 8. Saturation Characteristics

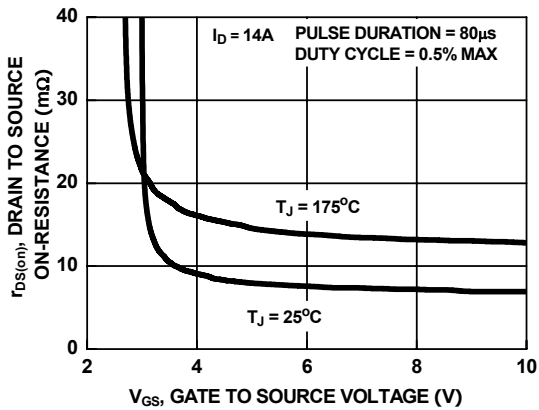


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

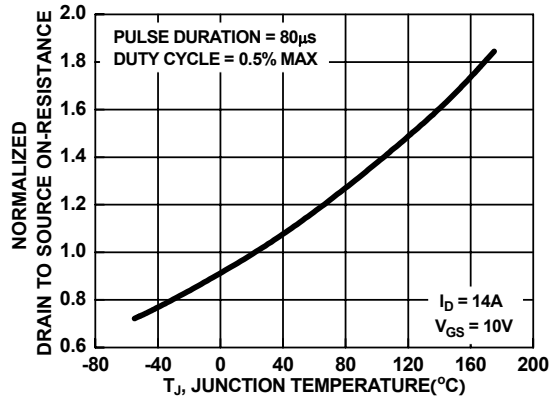


Figure 10. Normalized Drain to Source On-Resistance vs Junction Temperature

## Typical Characteristics

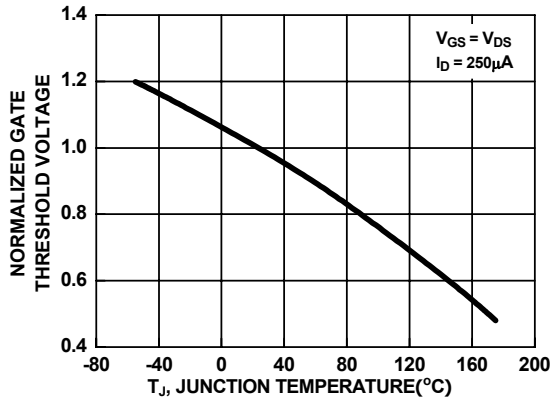


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

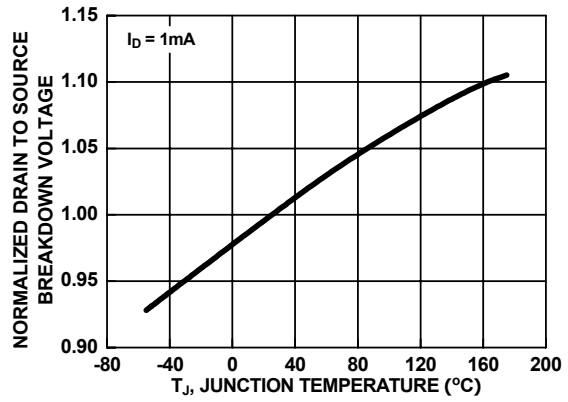


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

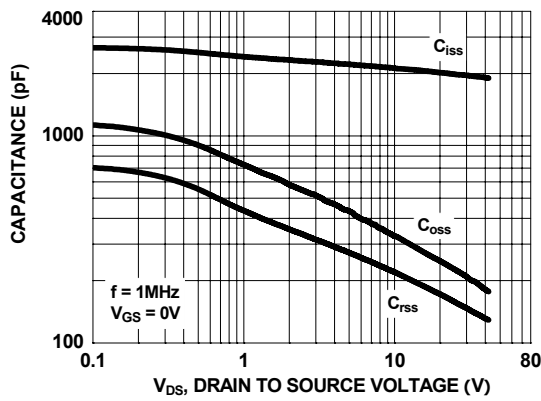


Figure 13. Capacitance vs Drain to Source Voltage

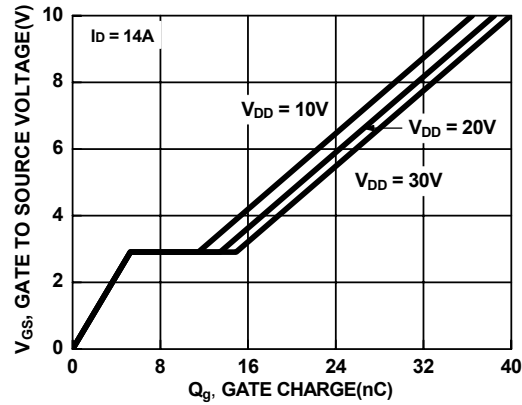





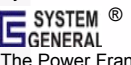


Figure 14. Gate Charge vs Gate to Source Voltage



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